Small Instrumentation Modules

SIM914 — 350 MHz, 2-channel preamplifier

- · DC to 350 MHz bandwidth
- · Two independent amplifier channels
- · Voltage gain of 5 (14 dB) per channel
- 6.4 nV/√Hz input noise
- · 3 ns overload recovery
- · Excellent phase linearity

• SIM914 ... \$675 (U.S. list)





- SIM914 350 MHz Preamplifier

The SIM914 dual-channel, 350 MHz preamplifier contains two wide-bandwidth, DC-coupled amplifiers, each with a gain of 5 (14 dB). Its fast rise time, low noise and excellent DC accuracy make it an ideal instrument for amplifying signals like those from photomultiplier tubes and photodiodes.

The gain stages of several SIM914 can be cascaded without creating oscillation problems. Input clamping gives a 3 ns recovery time from a 10× overload.

A wide bandwidth and $50~\Omega$ input and output impedance ensure a linear phase response across the entire frequency range, preserving pulse shapes.

Specifications

Amplifier channels

Inputs, outputs 50 Ω , DC coupled Bandwidth DC to 350 MHz

Rise/fall time 1 ns

Voltage gain 5 per channel (14 dB)

Input noise $6.4 \text{ nV/}\sqrt{\text{Hz (typ.)}}$

Operating range $\pm 200 \text{ mV(inputs)}, \pm 1 \text{ V (outputs)}$

Propagation delay 2.7 ns

Recovery time 3 ns for $10 \times$ overload Input protection ± 50 V for <1 μs

 $\begin{array}{lll} \text{Output clamp} & \pm 1.6 \text{ V} \\ \text{Output overload detect} & \pm 1.3 \text{ V} \\ \text{Crosstalk} & -60 \text{ dB} \end{array}$

Operating temperature 0 °C to 40 °C, non-condensing Interface Serial via SIM interface

Connectors BNC (4 front)

DB15 (male) SIM Interface
Power ±5 VDC (100 mA max.)
Dimensions 1.5" × 3.6" × 7.0" (WHD)

Weight 1.4 lbs.

Warranty One year parts and labor

Ordering Information

SIM914 350 MHz preamplifier

\$675



Stanford Research Systems